

SLG55590 SLG55590A USB Host Charger Identification Analog Switches

General Description

The SLG55590/SLG55590A is a USB device that combines high speed USB switches with a USB host charger (dedicated charger) identification circuit. The device supports both the latest USB Battery Charging Specification Revision 1.2 including data contact detection and a set resistor bias for Apple* compliant devices as well as legacy USB D+/D- short detection using data line pull-up.

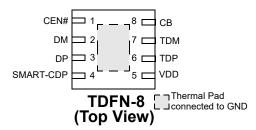
The SLG55590/SLG55590A can also support CDP mode (FAST charging and data communication available mode if smartphone can support CDP mode.)

The SLG55590/SLG55590A can also support low speed / full speed mouse/keyboard wake-up from S3 mode.

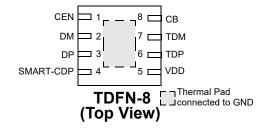
Features

- · High Speed USB Switching
- · Low 4.0pF (typ) On Capacitance
- Low 4.0Ω (typ) On Resistance
- Low 0.5Ω (typ) On Resistance Flatness
- 4.5V to 5.5V Supply Range
- Low Supply Current
- · Automatic Current-Limit Switch Control
- · Automatic USB Charger Identification Circuit
- CDP Support (active USB 2.0 data communication with 1.5A charging)
- Apple iPad* @ 2A charging current support
- Automatic CDP/SDP mode support with SMART-CDP=1 for "Always Data Communication"
- Chinese Telecom Standard YD/T 1591-2009 specification support
- · Forced dedicated charger support
- Samsung Galaxy Tab** charge scheme support
- Pb-Free / RoHS Compliant / Halogen-Free
- TDFN-8 Package

Pin Configuration - SLG55590

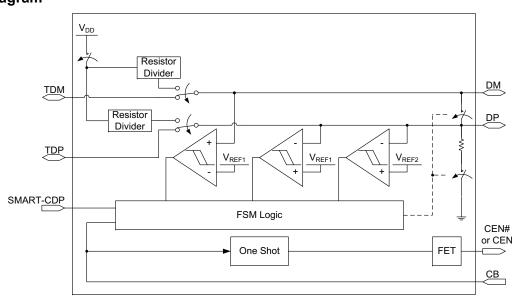


Pin Configuration - SLG55590A



- * Apple iPhone, iPad and iPod are trademarks of Apple Inc., registered in the U.S. and other countries.
- ** Samsung Galaxy Tab are trademarks of Samsung Electronics, registered in Korea and other countries.

Block Diagram





Pin Description - SLG55590

Pin#	Pin Name	Туре	Pin Description
1	CEN#	Output	P-FET Open Drain Output. Current Limit Switch (CLS) Control Output. CB changes from 0 to 1 or 1 to 0. CEN# will be high for 2 seconds (typ)
2	DM	Input/Output	USB Connector D-
3	DP	Input/Output	USB Connector D+
4	SMART-CDP	Input	Input Control logic (see truth table)
5	VDD	PWR	Power Supply. Connect a $0.1\mu\text{F}$ capacitor between VDD and GND as close as possible to the device.
6	TDP	Input/Output	Host USB Transceiver D+ Connection
7	TDM	Input/Output	Host USB Transceiver D- Connection
8	СВ	Input	Switch Control Bit 0 = autodetection charger identification active 1 = charging downstream port with active USB2.0 data communication mode with 1.5A support
9	Thermal Pad	GND	Ground

Pin Description - SLG55590A

Pin#	Pin Name	Туре	Pin Description
1	CEN	Output	N-FET Open Drain Output. Current Limit Switch (CLS) Control Output. CB changes from 0 to 1 or 1 to 0. CEN will be low for 2 seconds (typ)
2	DM	Input/Output	USB Connector D-
3	DP	Input/Output	USB Connector D+
4	SMART-CDP	Input	Input Control logic (see truth table)
5	VDD	PWR	Power Supply. Connect a $0.1\mu F$ capacitor between VDD and GND as close as possible to the device.
6	TDP	Input/Output	Host USB Transceiver D+ Connection
7	TDM	Input/Output	Host USB Transceiver D- Connection
8	СВ	Input	Switch Control Bit 0 = autodetection charger identification active 1 = charging downstream port with active USB2.0 data communication mode with 1.5A support
9	Thermal Pad	GND	Ground

Truth Table

СВ	SMART-CDP	Function
0	0 0 Forced dedicated charger with mouse/keyboard wakeup	
0 1 DCP autodetect with mouse/keyboard wakeup		DCP autodetect with mouse/keyboard wakeup
1	0	S0 charging with SDP only
1	1	S0 charging with CDP or SDP only (depending on external device) And, when Non-CDP phone is plugged in, the CDP mode will be changed automatically to SDP mode during handshaking protocol for supporting data communication.

Ordering Information

Part Number	Туре
SLG55590V	TDFN-8
SLG55590VTR	TDFN-8 - Tape and Reel
SLG55590AV	TDFN-8
SLG55590AVTR	TDFN-8 - Tape and Reel



Absolute Maximum Ratings

Parameter	Min.	Max.	Unit
Supply Voltage	-0.3	6.0	V
Continuous Current into any terminal	-30	+30	mA
Continuous Power Dissipation		954	mW
Operating Temperature Range	-40	85	°C
Junction Temperature		150	°C
Storage Temperature Range	-65	150	°C
Lead Temperature (Soldering, 10s)		260	°C

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics - Power Supply

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
W	Power Supply Pange	V _{CB} > V _{IH}	4.5	5.0	5.5	V
V _{DD}	Power Supply Range	V _{CB} = 0V	4.75		5.25	V
	Supply Current V _{DD} = 5V	CB=LOW, SMART-CDP=LOW (autodetect with wakeup)		120	140	μΑ
I _{DD}		CB = LOW, SMART-CDP = HIGH (autodetect with wakeup)	TBD	TBD	TBD	μА
		CB = HIGH, SMART- = LOW (SDP)		20	30	μА
		CB = HIGH, SMART- = HIGH (CDP)		40	70	μА

Electrical Characteristics - Analog Switch

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V_{DP}, V_{DM}	Analog signal Range		0		V_{DD}	V
		$V_{DD} = -0.4V$ to 0.4V, I = 10mA		3.5		Ω
R _{ON}	On Resistance TDP/TDM Switch	$V_{DP} = V_{DM} = 0V \text{ to } 3.3V$ $V_{DD} = 5V$		4.0	7	Ω
ΔR _{ON}	On Resistance Match between channels TDP/TDM Switch	$V_{DD} = 5.0V$ $V_{DP} = V_{DM} = 400$ mV $I_{DP} = I_{DM} = 10$ mA		0.1		Ω
R _{FLAT}	On Resistance flatness TDP/TDM Switch	$V_{DD} = 5.0V$ $V_{DP} = V_{DM} = 0V \text{ to } V_{DD}$ $I_{DP} = I_{DM} = 10\text{mA}$		0.5		Ω
R _{SHORT}	On Resistance of TDP/TDM Short	$V_{CB} = 0V$ $V_{DP} = 1V$ $I_{DP} = I_{DM} = 10mA$		50	70	Ω
I _{TDPOFF} , I _{TDMOFF}	Off-Leakage Current	$V_{DD} = 3.6V$ $V_{DP} = V_{DM} = 0.3V \text{ to } 3.3V$ $V_{TDP} = V_{TDM} = 3.3V \text{ to } 0.3V$ $V_{CB} = 0V$	-250		250	nA



 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
I _{DPON} , I _{DMON}	Off-Leakage Current	$V_{DD} = 3.6V$ $V_{DP} = V_{DM} = 3.3V$ to 0.3V $V_{CB} = V_{DD}$	-250		250	nA

Electrical Characteristics - Dynamic Performance

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
T _{ON}	Turn On Time	V_{TDP} or V_{TDM} = 1.5V R_L = 300 Ω C_L = 35pF	'	20	100	μs
T _{OFF}	Turn Off Time	V_{TDP} or $V_{TDM} = 1.5V$ $R_L = 300\Omega$ $C_L = 35pF$	'	1	5	μs
T _{PLH} , T _{PHL}	TDP/TDM Switch Propagation Delay	$R_L = R_S = 50\Omega$		60		ps
T _{SKEW}	Output Skew	Skew between DP and DM when connected to TDP and TDM $R_L = R_S = 50\Omega$		40		ps
C _{OFF}	TDP/TDM Off-Capacitance	f = 1MHz	'	2.0		pF
C _{ON}	DP/DM On-Capacitance	f = 240MHz	'	4.0	5.5	pF
BW	-3dB Bandwidth	$R_L = R_S = 50\Omega$		1000		MHz
V _{ISO}	Off-Isolation	V_{TDP} , V_{DP} = 0dBm R_L = R_S =5 0 Ω f = 250MHz		-20		dB
V _{CT}	Crosstalk	$V_{TDP_i}V_{DP} = 0 dBm$ $R_L = R_S = 50\Omega$ $f = 250MHz$		-25		dB

Electrical Characteristics - Internal Resistors

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
R _{PD}	DP/DM Short Pull-down		350	500	700	kΩ
RT _{RP}	RP1/RP2 Ratio		0.8544	0.863	0.872	Ratio
R_{RP}	RP1 + RP2 Resistance		69.75	93.0	115.18	kΩ
RT _{RM}	RM1/RM2 Ratio		1.485	1.5	1.515	Ratio
R _{RM}	RM1 + RM2 Resistance		93.75	125.0	156.25	kΩ

Electrical Characteristics - Logic Input CB

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

	Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
Ī	V_{IH}	CB Input Logic High		1.4			V
Ī	V _{IL}	CB Input Logic Low				0.4	V
	I _{IN}	CB Input Leakage Current	V_{DD} = 5.5V 0 \leq V_{CB} \leq V_{IL} or V_{IH} \leq V_{CB} \leq V_{DD}	-1		1	μА



Electrical Characteristics - Logic Input SMART-CDP

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{IH}	SMART-CDP input Logic High		3.0			V
V _{IL}	SMART-CDP input Logic Low				0.8	V
I _{IN}	SMART-CDP Input Leakage Current	V _{DD} = 5.5V 0V < V _{SMART-CDP} < V _{IL} or V _{IH} < V _{SMART-CDP} < V _{DD}	-1		1	μΑ

Electrical Characteristics - CEN#/CEN Outputs

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

Parameter	Description	Condition/Note	Min.	Тур.	Max.	Unit
T _{VBT}	V _{BUS} Toggle Time CB = Logic 0 to Logic 1 or Logic 1 to Logic 0		1.5	2.0	2.5	s
V _{OH_CEN#}	CEN# Output Logic High Voltage	I# Output Logic High Voltage CB = Logic 0 to Logic 1 I _{SOURCE} = 2mA V				V
I _{OUT_CEN#}	CEN# Output Leakage Current	V _{DD} = 5.5V V _{CEN#} = 0V or CEN# deasserted			1	μΑ
V _{OL_CEN}	CEN Output Logic Low Voltage	CB = Logic 0 to Logic 1 I _{SINK} = 2mA			0.4V	٧
I _{OUT_CEN}	CEN Output Leakage Current	V _{DD} = 5.5V V _{CEN} = 5.5V or CEN deasserted			1	μΑ

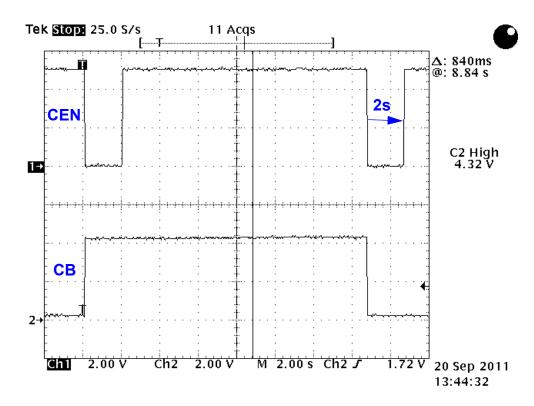
Electrical Characteristics - ESD Protection

 V_{DD} = 4.5V to 5.5V, T_A = 25°C (unless specified otherwise)

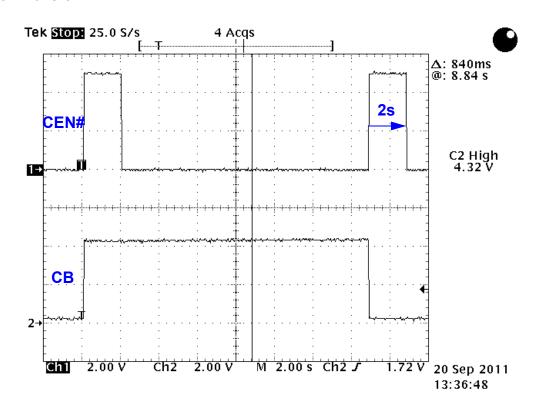
Parame	ter Description	Condition/Note	Min.	Тур.	Max.	Unit
V _{ESD}	ESD Protection Level (DP and DM Only)	Human Body Model		±8		kV
V _{ESD}	ESD Protection Level (All other pins)	Human Body Model		±2		kV



CEN Function Waveform



CEN# Function Waveform





Package Top Marking System Definition

	8 7 6 5	
Part ID	XXA	Assembly Code
Datecode	DD L	Lot
	\mathbb{R}	Revision
	1 2 3 4	

XX - Part ID Field: identifies the specific device configuration

A - Assembly Code Field: Assembly Location of the device.

DD - Date Code Field: Coded date of manufacture

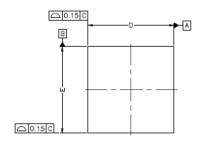
L - Lot Code: Designates Lot #

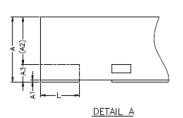
R - Revision Code: Device Revision

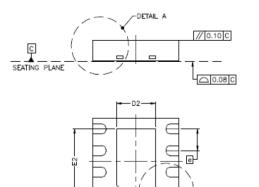


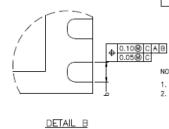
Package Drawing and Dimensions

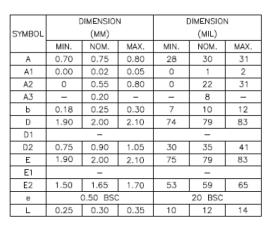
8 Lead TDFN Package JEDEC MO-229, Variation WCCD











- REFER TO JEDEC STD: MO-229.
 DIMENSION "b" APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.15MM AND 0.30MM FROM THE TERMINAL TIP. IF THE TERMINAL HAS OPTIONAL RADIUS ON THE OTHER END OF THE TERMINAL, THE DIMENSION B SHOULD NOT BE MEASURED IN THAT RADIUS AREA.

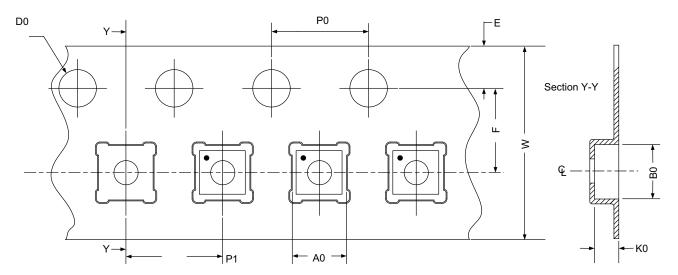


Tape and Reel Specifications

Package Type	# of Pins	Nominal Package Size [mm]	Max Units		Reel &	Leader (min)		Trailer (min)		Таре	Part
			per Reel	per Box	Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
TDFN 8L Green	8	2 x 2 x 0.75	3,000	3,000	178 / 60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	PocketBTM Length	PocketBTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge Index Hole to Pocket Center		Tape Width	
	A0	В0	K0	P0	P1	D0	E	F	w	
TDFN 8L Green	2.3	2.3	1.05	4	4	1.55	1.75	3.5	8	



Refer to EIA-481 specification

Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of $3.00~\text{mm}^3$ (nominal). More information can be found at www.jedec.org.

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